TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG32FU,TC7WG32FK

Dual 2-Input OR Gate

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at $V_{CC} = 3 V$

• High-speed operation: t_{pd} = 2.8 ns (typ.)

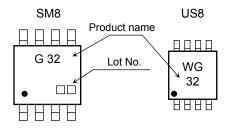
at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

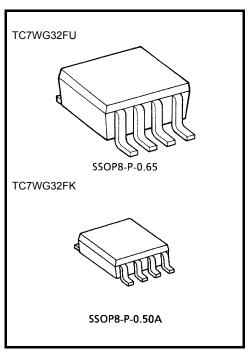
• Operating voltage range: V_{CC} = 0.9~3.6 V

• 5.5-V tolerant inputs

• 3.6-V power down protection outputs

Marking





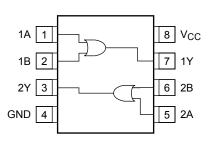
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	\/a	-0.5~4.6 (Note 1)	V
	Vout	-0.5~V _{CC} + 0.5 (Note 2)	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V _{CC} / ground current	Icc	±50	mA
Power dissipation	PD	300 (SM8) 200 (US8)	mW
Storage temperature	T _{stg}	-65~150	°C

Pin Assignment (top view)



Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

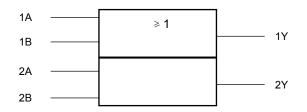
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0 V$

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: V_{OUT} < GND

IEC Logic Symbol



Truth Table

Inp	Outputs			
Α	В	Y		
L	L	L		
L	Н	Н		
Н	L	Н		
Н	Н	Н		

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	\/	0~3.6 (Note 4)	V	
	Vout	0~V _{CC} (Note 5)	\ \ \	
Output Current		±8.0 (Note 6)		
		±4.0 (Note 7)		
		±3.0 (Note 8)	mA	
	I _{OH} /I _{OL}	±1.7 (Note 9)	MA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 10: V_{CC} = 1.1~1.3 V

Note 11: $V_{CC} = 0.9 \text{ V}$

Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition			Ta = 25°C		Ta = -40~85°C		11-4				
		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit			
						V_{CC}	_	_	V _C C	_	
High level			_		1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	
	High level	I V _{IH}			1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_	
					1.65~ 1.95	V _{CC} × 0.65		_	V _{CC} × 0.65	_	
					2.3~2.7	1.7	_	_	1.7	_	
Input voltage					3.0~3.6	2.0	_	_	2.0	_	V
input voltage					0.9	_	_	GND	_	GND	v
					1.1~1.3	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	
	Low level	VIL		_		_	_	V _{CC} × 0.35	_	V _{CC} × 0.35	
		.=				_	_	V _{CC} × 0.35	_	V _{CC} × 0.35	
					2.3~2.7	_	_	0.7	_	0.7	
					3.0~3.6	_	_	0.8	_	0.8	
		Vон	V _{IN} = V _{IH} or V _{IL}	I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_	
	High level			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75		_	V _{CC} × 0.75	_	V
				I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
				$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_	
				I _{OH} = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
Outrout valtage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48	_	
Output voltage		Low level V _{OL}		$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	
1				I _{OL} = 0.3 mA	1.1~1.3	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
	Low level			I _{OL} = 1.7 mA	1.4~1.6	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
				I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45	_	0.45	
				I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4	
				I _{OL} = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4	
Input leakage cur	rent	I _{IN}	V _{IN} = 0~5.5 V		0~3.6	_	_	±0.1	_	±1.0	μА
Power off leakage	Power off leakage current I _{OFF} V _{IN} = 0~5.5 V V _{OUT} = 0~3.6 V		5 V ·3.6 V	0	_	_	1.0	_	10.0	μΑ	
Quiescent supply	Quiescent supply current I_{CC} $V_{IN} = V_{CC}$ or GND		or GND	3.6	_	_	1.0	_	10.0	μА	

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AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
		C _L = 10 pF,	0.9	_	19.8	_	_	_	
			1.1~1.3	_	10.1	18.7	1.0	34.5	
			1.4~1.6	_	5.9	8.9	1.0	10.8	
		$R_L^- = 1 M\Omega$	1.65~ 1.95	1	4.5	6.4	1.0	6.9	
			2.3~2.7	1	3.1	4.2	1.0	4.7	
			3.0~3.6		2.3	3.4	1.0	4.0	
			0.9		22.5		_	_	
	^t pLH ^t pHL	C_L = 15 pF, R_L = 1 M Ω	1.1~1.3		11.6	21.5	1.0	37.2	ns
Propagation delay time			1.4~1.6		6.6	9.8	1.0	12.0	
Tropagation delay time			1.65~ 1.95		5.0	7.1	1.0	7.3	
			2.3~2.7		3.5	4.5	1.0	5.1	
			3.0~3.6		2.8	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		30.0		_	_	
			1.1~1.3		15.0	29.6	1.0	56.0	
			1.4~1.6	_	8.5	13.1	1.0	15.9	
			1.65~ 1.95	_	6.3	9.2	1.0	9.6	
			2.3~2.7		4.3	5.7	1.0	6.1	
			3.0~3.6		3.5	4.4	1.0	4.8	
Input capacitance	C _{IN}		3.6		3	_	_		pF
Power dissipation capacitance	C _{PD}	(Note13)	0.9 ~ 3.6	_	11	_			pF

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

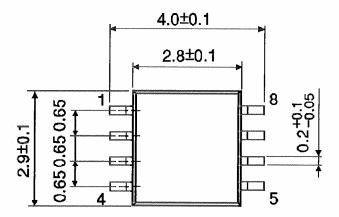
Average operating current can be obtained by the equation:

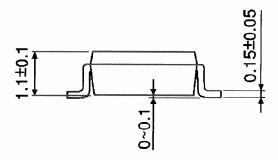
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

Package Dimensions

TOSHIBA

SSOP8-P-0.65 Unit: mm



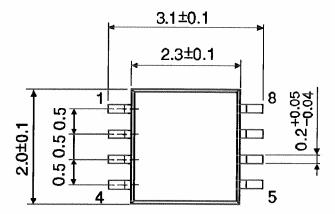


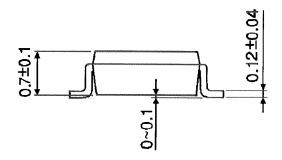
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Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A Unit: mm





6

Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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